OP140, OP145 Series



Features:

- IR-transmissive plastic package
- Side-looking package for space-limited applications
- Wide irradiance pattern
- Mechanically and spectrally matched to other OPTEK products



Description:

Each device in this series is a high intensity gallium arsenide infrared emitting diode that is suited for use as a PCBoard mounted slotted switch or an easy mount PCBoard interrupter.

Each **OP140** (A, B, C, D) and **OP145** (A, C) device is a domed-lens 935 nm diode that is molded in an IR-transmissive plastic side-looking package.

OP140 is mechanically and spectrally matched to the OP550 series of phototransistors and the OP560 series of photodarlingtons. OP145 is mechanically and spectrally matched to the OP555 and OP565 series devices.

Please refer to Application Bulletins 208 and 210 for additional design information and reliability (degradation) data.

Applications:

- Space-limited applications
- PCBoard mounted slotted switch
- PCBoard interrupter

	Orde	ring Informa	tion	
Part Number	LED Peak Wavelength	Lens Type	Total Beam Angle	Lead Length
OP140A				
OP140B				
OP140C	935 nm	Domed	40°	min of 0.50"
OP140D	935 NM	Domed	40	Mill 01 0.50
OP145A				
OP145C				

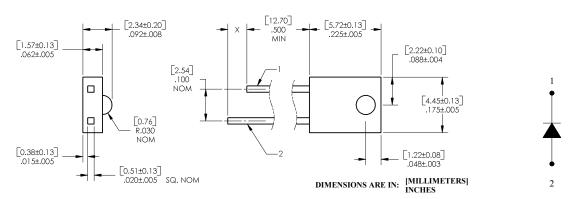


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OP140, OP145 Series



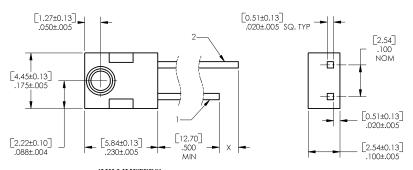
OP140 (A, B, C, D)



Pin#	LED	Sensor
1	Cathode	Emitter/Anode
2	Anode	Collector/Cathode

OP145 (A, C)





DIMENSIONS ARE IN: [MILLIMETERS] INCHES

Pin#	LED	Sensor
1	Cathode	Emitter/Anode
2	Anode	Collector/Cathode

CONTAINS POLYSULFONE

To avoid stress cracking, we suggest using ND Industries' **Vibra-Tite** for thread-locking. **Vibra-Tite** evaporates fast without causing structural failure in OPTEK'S molded plastics.

OP140, OP145 Series



Electrical Specifications

Absolute Maximum Ratings (T _A = 25° C unless otherwise noted)				
Storage and Operating Temperature Range	-40° C to +100° C			
Reverse Voltage	2.0 V			
Continuous Forward Current	50 mA			
Peak Forward Current	3.0 A			
Lead Soldering Temperature [1/16 inch (1.6 mm) from case for 5 seconds with soldering iron] ⁽¹⁾	260° C			
Power Dissipation ⁽²⁾	100 mW			

Electrical	Electrical Characteristics (T _A = 25° C unless otherwise noted)						
SYMBOL	PARAMETER	MIN	TYP	MAX	UNITS	TEST CONDITIONS	
nput Diod	e						
E _{E (APT)}	Apertured Radiant Incidence OP140A, OP145A OP140B OP140C, OP145C OP140D	0.40 0.30 0.20 0.10	- - -	- 0.55 0.40 -	mW/cm²	I _F = 20 mA ⁽³⁾	
V _F	Forward Voltage	-	-	1.60	V	I _F = 20 mA	
I _R	Reverse Current	-	-	100	μΑ	V _R = 2.0 V	
λ_{P}	Wavelength at Peak Emission	-	935	-	nm	I _F = 10 mA	
В	Spectral Bandwidth between Half Power Points	-	50	-	nm	I _F = 10 mA	
$\lambda_P/\Delta T$	Spectral Shift with Temperature	-	±0.30	-	nm/°C	I _F = Constant	
$\theta_{\sf HP}$	Emission Angle at Half Power Points	-	40	-	Degree	I _F = 20 mA	
t _r	Output Rise Time	-	1000	-	ns	I _{F(PK)} =100 mA, PW=10 μs, and D.C.=10.0%	
t _f Notes:	Output Fall Time	-	500	-	ns		

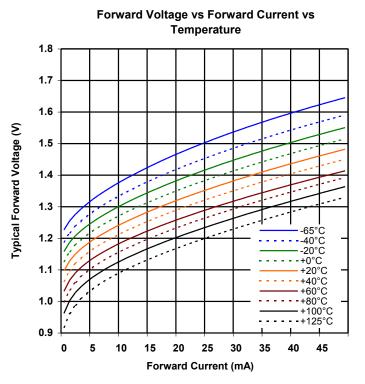
- 1. RMA flux is recommended. Duration can be extended to 10 seconds maximum when flow soldering. A maximum of 20 grams force may be applied to the leads when soldering.
- 2. Derate linearly 1.33 mW/° C above 25° C.
- 3. E_{E(APT)} is a measurement of the average apertured radiant energy incident upon a sensing area 0.180" (4.57 mm) in diameter perpendicular to and centered on the mechanical axis of the lens and 0.653" (6.60 mm) from the lens tip. E_{E(APT)} is not necessarily

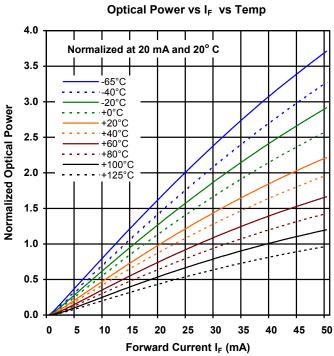
OP140, OP145 Series



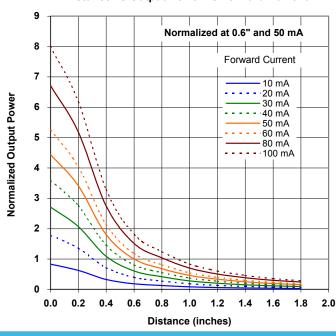
Performance

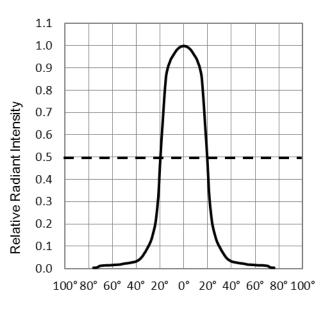
OP140, OP145 (A, B, C, D)





Distance vs Output Power vs Forward Current





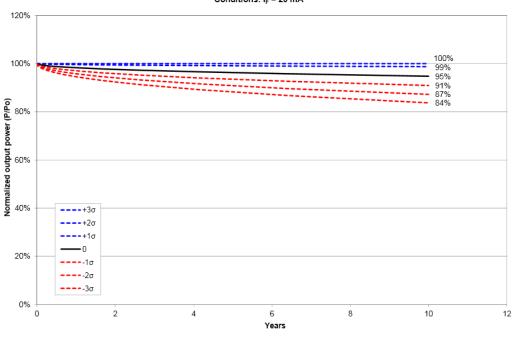
θ - Angular Displacement - Degrees

OP140, OP145 Series



Performance

Degradation curves of OP140 +/- 3 standard deviations Conditions: I_F = 20 mA



Spectral Response

